# $\propto$ LINEAR 

## DESCRIPTION

## DEMO MANUAL DC355/DC356 NO-DESIGN SWITCHER

## LT1959 Monolithic 4A Switcher 5 V to 15 V Input 1.8V Output

Demonstration circuits DC355 and DC356 are complete DC/DC step-down regulators using the LT ${ }^{6} 1959$ constant frequency, high efficiency converter in 7-pin DD (DC356) and SO-8 (DC355) packages. These circuits are primarily used in personal computers, disk drives, portable
handheld devices and, in larger systems, as local onboard regulators. High frequency switching allows the use of small inductors, making this all surface mount solution ideal for space conscious systems.
$\mathbf{1 7}$, LTC and LT are registered trademarks of Linear Technology Corporation.

## PERFORMANCE SUMMARY

$T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{I N}=5 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=2 \mathrm{~A}, \mathrm{~V}_{0 U T}=1.8 \mathrm{~V}, \overline{\text { SHDN }}$ and SYNC pins open, unless otherwise specified.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :--- | :--- | :---: | :---: | :---: | :---: |
| Output Voltage | (Note 1) | 1.75 | 1.8 | 1.85 | V |
| Maximum ILOAD | (Note 2) | 4.3 |  |  | A |
| Input Voltage Range |  | 4.5 |  | 15 | V |
| Switching Frequency |  | 460 | 500 | 540 | kHz |
| Output Ripple Voltage |  |  | 25 |  | mV P-P |
| Line Regulation | 5 V to 15V |  | 4 |  | mV |
| Load Regulation | ILOAD $=10 \mathrm{~mA}$ to 4A | 2.3 | 2.38 | 2.46 | mV |
| $\overline{\text { SHDN Lockout Threshold }}$ |  | 0.15 | 0.37 | 0.6 | V |
| $\overline{\text { SHDN Shutdown Threshold }}$ |  | 580 |  | 1000 | kHz |
| Synchronization Range | DC355 Only |  | 20 |  | $\mu \mathrm{~A}$ |
| Supply Current | $\overline{\text { SHDN }}=0 \mathrm{~V}$ |  |  |  |  |

Note 1: Output voltage variations include $\pm 1 \%$ tolerance of feedback
divider network.
Note 2: For DC355, additional thermal restrictions apply.

## BOARD PHOTOS

DC355 Component Side


DC356 Component Side


## DEMO MANUAL DC355/DC356 <br> NO-DESIGN SWITCHER

## TYPICAL PGRFORMANCE CHARACTERISTICS

### 1.8V Output Efficiency



Temperature Rise vs Load Current


## PACKAGE ARD SCHEMATIC DIAGRAMS



## DEMO MANUAL DC355/DC356

## PARTS LISTS

## DC355

| REFERENCE DESIGNATOR | QUANTITY | PART NUMBER | DESCRIPTION | VENDOR | TELEPHONE |
| :---: | :---: | :---: | :---: | :---: | :---: |
| C1 | 0 |  | Optional Capacitor |  |  |
| C2 | 1 | 08055C332MAT2S | 3300pF 50V X7R Chip Capacitor | AVX | (843) 946-0362 |
| C3 | 1 | GRM235Y5V106Z | 10^F 25V Y5V Chip Capacitor | Murata | (770) 436-1300 |
| C4 | 1 | 0805ZC105MAT2S | $1 \mu \mathrm{~F}$ 10V X7R Chip Capacitor | AVX | (843) 946-0362 |
| C5 | 1 | TPSD107M010R0080 | 100 $\mathrm{F}^{\text {F 1 }}$ (VV TPS Tantalum Capacitor | AVX | (207) 282-5111 |
| C6 | 1 | 0603ZG474MAT3S | $0.47 \mu \mathrm{~F}$ 10V Y5V Chip Capacitor | AVX | (843) 946-0362 |
| C7 | 1 |  | Optional Capacitor |  |  |
| D1 | 1 | MBRD835L | SMT Diode | ON Semiconductor | (602) 244-6600 |
| D2 | 1 | MMBD914LT1 | 1N914 Diode | ON Semiconductor | (602) 244-6600 |
| D3 | 1 |  | Optional Diode |  |  |
| E1 to E6 | 6 | 2501-2 | Pad Turret | Mill-Max | (516) 922-6000 |
| R1 | 1 | CR10-332JM | 3.3k 1/8W 5\% Chip Resistor | AAC | (714) 255-9186 |
| R2 | 1 | CR10-1821F-T | 1.82k 1/8W 1\% Chip Resistor | AAC | (714) 255-9186 |
| R3 | 1 | CR10-4991F-T | 4.99k 1/8W 1\% Chip Resistor | AAC | (800) 508-1521 |
| L1 | 1 | D03316P-682 | $6.8 \mu \mathrm{H} 20 \%$ Inductor | Coilcraft | (847) 639-6400 |
| U1 | 1 | LT1959CS8 | S0-8 Linear IC | LTC | (408) 432-1900 |

DC356

| REFERENCE DESIGNATOR | QUANTITY | PART NUMBER | DESCRIPTION | VENDOR | TELEPHONE |
| :---: | :---: | :---: | :---: | :---: | :---: |
| C1 | 0 |  | Optional Capacitor |  |  |
| C2 | 1 | 08055C332MAT2S | 3300pF 50V X7R Chip Capacitor | AVX | (843) 946-0362 |
| C3 | 1 | GRM235Y5V106Z | 10ㄱF 25V Y5V Chip Capacitor | Murata | (770) 436-1300 |
| C4 | 1 | 0805ZC105MAT2S | $1 \mu \mathrm{~F}$ 10V X7R Chip Capacitor | AVX | (843) 946-0362 |
| C5 | 1 | TPSD107M010R0080 | 100 F F 10V TPS Tantalum Capacitor | AVX | (207) 282-5111 |
| C6 | 1 | 0603ZG474MAT3S | $0.47 \mu \mathrm{~F}$ 10V Y5V Chip Capacitor | AVX | (843) 946-0362 |
| C7 | 1 |  | Optional Capacitor |  |  |
| D1 | 1 | MBRD835L | SMT Diode | ON Semiconductor | (602) 244-6600 |
| D2 | 1 | MMBD914LT1 | 1N914 Diode | ON Semiconductor | (602) 244-6600 |
| D3 | 1 |  | Optional Diode |  |  |
| E1 to E6 | 6 | 2501-2 | Pad Turret | Mill-Max | (516) 922-6000 |
| R1 | 1 | CR10-332JM | 3.3k 1/8W 5\% Chip Resistor | AAC | (714) 255-9186 |
| R2 | 1 | CR10-1821F-T | 1.82k 1/8W 1\% Chip Resistor | AAC | (714) 255-9186 |
| R3 | 1 | CR10-4991F-T | 4.99k 1/8W 1\% Chip Resistor | AAC | (800) 508-1521 |
| L1 | 1 | D03316P-682 | 6.8 $\mu \mathrm{H}$ 20\% Inductor | Coilcraft | (847) 639-6400 |
| U1 | 1 | LT1959CR | 7-Pin DD Pak Linear IC | LTC | (408) 432-1900 |

## OPERATION

## DC355 vs DC356 (Temperature vs Package Size)

The DC355 and DC356 demonstration boards are intended for evaluation of the LT1959 switching regulator in the S0-8 and 7-pin DD packages, respectively. The 7-pin DD package used on DC356 has no SYNC pin. The primary reason for choosing the SO-8 over the DD package is board space. The DC356 (DD package) occupies an active board area of approximately 0.75 square inches. By optimizing the DC355 board, using a Sumida coil and removing the layout options, a total active area of 0.4 square inches can be achieved. The DD package is more suitable for higher power or higher ambient temperature applications. Although both boards will supply 4A of output current, DC355 must be thermally derated to 3A continuous current at $22^{\circ} \mathrm{C}$ ambient to prevent excessive die temperatures. DC356 can run at $60^{\circ} \mathrm{C}$ ambient at 4 A output current. However, the SO-8 package can be used for dynamic loads up to the full rated switch current.

## LT1959 Operation

The LT1959 data sheet gives a complete description of the part, operation and applications information. The data sheet should be read in conjunction with this demo manual.

## Hook-Up

Solid turret terminals are provided for easy connection to supplies and test equipment. Connect a 0 V to $15 \mathrm{~V}, 4.5 \mathrm{~A}$ power supply across the $\mathrm{V}_{\text {IN }}$ and GND terminals and the load across the $\mathrm{V}_{\text {OUT }}$ and GND terminals. When measuring load/line regulation, remember to Kelvin connect to the turrets. Also, when measuring output ripple voltage with an oscilloscope probe, the wire from the probe to the ground clip will act as an antenna, picking up excessive noise. For improved results, the test hook should be removed from the tip of the probe. The tip should be touched against the output turret, with the bare ground shield pressed against the ground turret. This reduces the noise seen on the waveform.

## Shutdown

For normal operation, the $\overline{\mathrm{SHDN}}$ pin can be left floating. SHDN has two output-disable modes: lockout and shutdown. When the pin is taken below the lockout
threshold, switching is disabled. This is typically used for input undervoltage lockout. Grounding the SHDN pin places the LT1959 in shutdown mode. This reduces total board supply current to $20 \mu \mathrm{~A}$.

## Synchronization

Synchronization is available on DC355 only. For normal demo board operation, the SYNC pin can be left floating. If it is not used in the application, it is advisable to tie this pin to ground. To synchronize switching to an external clock, apply a logic-level signal to the SYNC pin. The amplitude must be from a logic low to greater than 2.2 V , with a duty cycle between $10 \%$ and $90 \%$. The synchronization frequency must be greater than the free-running oscillator frequency and less than 1 MHz . Additional circuitry may be required to prevent subharmonic oscillation. Refer to the LT1959 data sheet for more details.

## COMPONENTS

## Inductor L1

The inductor is a Coilcraft D03316P-682, a $6.8 \mu \mathrm{H}$ unshielded ferrite unit. It was selected for its low cost, small size and $4.6 \mathrm{Al}_{\text {SAT }}$ rating. The equivalentCoiltronics UP2-6R8 unit can be substituted. If board space is at a premium and higher ripple current is acceptable, solder pads are available for the Sumida CD43-1R8 inductor. This $1.8 \mu \mathrm{H}$ unit has a $2.9 \mathrm{~A} \mathrm{I}_{\text {SAT }}$ rating. Ripple at $5 \mathrm{~V}_{\text {IN }}$ is $\pm 0.6 \mathrm{~A}$. This gives a maximum output current of $(4.5 \mathrm{~A}-0.6 \mathrm{~A})=3.9 \mathrm{~A}$.

## Input/Output Capacitors C3, C5, C6 and C7

The input capacitor C3 is a Tokin ceramic capacitor. It was selected for its small size, high voltage rating and low ESR (effective series resistance). The input ripple current for a buck converter is high, typically $\mathrm{I}_{\mathrm{OUT}} / 2$. Tantalum capacitors become resistive at higher frequencies, requiring careful ripple-rating selection to prevent excessive heating. Ceramic capacitors' ESL (effective series inductance) tends to dominate their ESR, making them less susceptible to ripple-induced heating.

# DEMO MANUAL DC355/DC356 <br> NO-DESIGN SWITCHER 

## OPERATION

The output capacitor C 5 is an AVX tantalum capacitor. A ceramic is not recommended as the main output capacitor, since loop stability relies on a resistive characteristic at higher frequencies to form a zero. The AVX TPS series was specifically designed to have the low ESR required in switch-mode power supplies. At switching frequencies, ripple voltage is more a function of ESR than of absolute capacitance value. If lower output ripple voltage is required, use the optional capacitor C 7 to reduce ESR rather than increasing the capacitance of C5. For very low ripple, an additional LC filter in the output may be a less expensive solution. The output contains very narrow voltage spikes because of the parasitic inductance of C 5 . A small ceramic capacitor, C6, removes these spikes on the demo board. In application, trace inductance and local bypass capacitors will perform this function, negating the need for C 6 .

## Catch Diode D1

Use diodes designed for switching applications, with adequate current rating and fast turn-on times, such as Schottky or ultrafast diodes. In selecting a diode, the basic parameters of interest are forward voltage, maximum reverse voltage, average operating current and peak current. Lower forward voltage yields higher circuit efficiency and lowers power dissipation in the diode. The MBRD835L has a maximum forward drop of 0.4 V at 3 A . The reverse voltage rating must be greater than the input voltage. Average diode current is always less than output current, but under a shorted output condition, diode current can equal the switch current limit. If the application must withstand this condition, the diode must be rated for maximum switch current.

## Compensation: C1, C2 and R1

A detailed discussion of frequency compensation can be found in the LT1959 data sheet. R1 + C2 from $V_{C}$ to ground give a stable loop response over a wide range of input and output conditions. Optional capacitor C 1 is included for optimization of the dynamic response for a specific application.

## Boost Voltage: D2, D3 and C4

A boost voltage of at least 2.8 V is required throughout the on-time of the switch to guarantee that it remains saturated. For output voltages above 3.3V, diode D2 can replace D3 and provide sufficient boost voltage to C4.

## PCB LAYOUT

In many cases, the layout of the demonstration board may be dropped directly into the application with minimal changes. If not, there are several precautions that must be taken when laying out high frequency converter circuits. The high frequency switching path runs from ground, through C 3 , to the $\mathrm{V}_{\text {IN }}$ pin of the LT1959, out of the SW pin, through D1 and back to ground. This loop acts as an antenna and will radiate noise if not kept as short as possible. Also, at higher switching currents, the associated trace inductance can cause excessive voltage spikes across the switch. The use of a ground plane will reduce many noise problems. The ground pin of the LT1959 contains some high frequency signal currents, but more importantly, it is the OV reference for the output voltage. Connect the ground pin directly to the ground plane. The FB and $\mathrm{V}_{\mathrm{C}}$ components should be kept away from the power components as much as possible. The ground for these components should be separated from power grounds. Run a Kelvin sense line to $\mathrm{V}_{\text {OUT }}$ as required but keep the divider network close to the LT1959 to prevent noise pickup on the FB node. Noise pickup on the $V_{C}$ pin appears as various problems, including poor load regulation, subharmonic oscillation and instability. Thermal management must also be considered. The SO-8 package has a fused ground pin. Soldering this pin to a large copper area will significantly reduce its thermal resistance. Solder-filled feedthroughs close to the ground pin provide a good thermal path to the ground plane. For the DD package, the grounded tab should be treated in the same manner. For more information or advice, contact the LTC Applications department.

## DEMO MANUAL DC355/DC356

## PCB LAYOUT AחD FILI (DC355)



Component Side Silkscreen


Component Side Solder Mask


Component Side


Component Side Paste Mask


Solder Side


Solder Side Solder Mask

## PCB LAYOUT AחD FILm (DC356)



Component Side Silkscreen


Component Side Solder Mask


Solder Side


Component Side


Component Side Paste Mask


Solder Side Solder Mask

## PC FAB DRAUINGS



NOTES: UNLESS OTHERWISE SPECIFIED

1. MATERIAL: FR4 OR EQUIVALENT EPOXY,

2 OZ COPPER CLAD, THICKNESS $0.062 \pm 0.006$
TOTAL OF 2 LAYERS
2. FINISH: ALL PLATED HOLES 0.001 MIN/0.0015 MAX

COPPER PLATE, ELECTRODEPOSITED TIN-LEAD COMPOSITION
BEFORE REFLOW, SOLDER MASK OVER BARE COPPER (SMOBC)
3. SOLDER MASK: BOTH SIDES USING SR1020 OR EQUIVALENT
4. SILKSCREEN: USING WHITE NONCONDUCTIVE EPOXY INK
5. ALL DIMENSIONS IN INCHES
6. SCORING


| SYMBOL | DIAMETER | NUMBER <br> OF HOLES |
| :---: | :---: | :---: |
| A | 0.020 | 38 |
| B | 0.025 | 7 |
| C | 0.072 | 2 |
| $D$ | 0.095 | 6 |
| TOTAL HOLES |  |  |
| 53 |  |  |

## DC356



NOTES: UNLESS OTHERWISE SPECIFIED

1. MATERIAL: FR4 OR EQUIVALENT EPOXY,

2 OZ COPPER CLAD, THICKNESS $0.062 \pm 0.006$
TOTAL OF 2 LAYERS
2. FINISH: ALL PLATED HOLES 0.001 MIN/0.0015 MAX

COPPER PLATE, ELECTRODEPOSITED TIN-LEAD COMPOSITION
BEFORE REFLOW, SOLDER MASK OVER BARE COPPER (SMOBC)
3. SOLDER MASK: BOTH SIDES USING GREEN SR1020 OR EQUIVALENT
4. SILKSCREEN: USING WHITE NONCONDUCTIVE EPOXY INK
5. ALL DIMENSIONS IN INCHES
6. SCORING


| SYMBOL | DIAMETER | NUMBER <br> OF HOLES |
| :---: | :---: | :---: |
| A | 0.020 | 30 |
| B | 0.072 | 2 |
| C | 0.095 | 5 |
|  | TOTAL HOLES | 37 |
| DC356 FD |  |  |



## Linear Technology Corporation <br> LT1959CR

| Item | Qty | Reference | Part Description | Manufacture / Part \# |
| :---: | :---: | :---: | :---: | :---: |
| 1 | 0 | C1 | CAP., OPTIONAL |  |
| 2 | 1 | C2 | CAP., CHIP X7R .033uF 50V | AVX 08055C333MAT2S 0805 |
| 3 | 1 | C3 | CAP., CHIP Y5V 10uF 25V | TAIYOYUDEN TMK325F106ZH 121 |
| 4 | 1 | C4 | CAP., CHIP X7R 1uf 10V | AVX 0805ZC105MAT2S 0805 |
| 5 | 1 | C5 | CAP., TANT TPS 100uF 10V | AVX TPSD107M010R0065 CASE-L |
| 6 | 1 | C6 | CAP., CHIP Y5V 0.47uF 10V | AVX 0603ZG474ZAT3S 0603 |
| 7 | 0 | C7 | CAP., OPTIONAL |  |
| 8 | 1 | D1 | DIODE, SMT MBRD835L | MOTOROLA MBRD835L DPAK |
| 9 | 0 | D2 | DIODE, OPTIONAL |  |
| 10 | 1 | D3 | DIODE, 1N914 | MOTOROLA MMBD914LT1 SOT2 |
| 11 | 6 | E1-E6 | TURRET, PAD | MILL-MAX 2501-2 PAD. 092 |
| 12 | 1 | R1 | RES., CHIP 3.3K 1/8W 5\% | AAC CR10-332JM 0805 |
| 13 | 1 | R2 | RES., CHIP 1.21K 1/8W 1\% | AAC CR10-1211FM 0805 |
| 14 | 1 | R3 | RES., CHIP 2.49K 1/8W 1\% | AAC CR10-2491FM 0805 |
| 15 | 1 | L1 | INDUCTOR, 6.8uH 20\% | COILCRAFT DO3316P-682 |
| 16 | 1 | U1 | IC., LINEAR LT1959CR | LINEAR LT1959CR 7LEAD-DD |
| 17 | 1 |  | PRINTED CIRCUIT BOARD | DEMO BOARD DC356A |
| 18 | 1 |  | STENCIL | STENCIL DC356A |

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